



Product Change Notice

Micron PCN: 31151

Date: 2/21/2014

Revision, 2/24/2014; This document supersedes the original PCN #31151, dated 2/21/2014. Updated the link provided in the Method of Identification field.

Type of Change:	Manufacturing Site Change	
Title of Change:	50nm RLDRAM 3 (F67R) Fab Site addition of Virginia, USA	
Description of Change:	Fabrication of Micron's 50nm RLDRAM 3 (F67R) parts will be produced from Singapore (Fab 7) and Virginia, USA (Fab 6).	
Reason for Change:	Optimization of Manufacturing Efficiency	
Contact Information:	<u>Marketing Contact</u> SHERRY GRAY Micron Semiconductor Prds SGRAY@MICRON.COM	<u>Engineering Contact</u> DENZIL ROGERS Micron Semiconductor Prds DENZILROGERS@MICRON.COM

Product Affected: All F67R parts

Affected Micron Part Number

MT44K16M36RB-093E:A	MT44K32M18RB-125E:A	MT44K32M18RB-093 IT:A
MT44K16M36RB-107E:A	MT44K16M36RB-093E IT:A	MT44K64M18RCT-125E IT:A
MT44K16M36RB-107:A	MT44K32M18RB-107:A	MT44K64M18RCT-125 IT:A
MT44K16M36RB-093:A	MT44K32M18RB-125:A	MT44K32M36RCT-125E:A
MT44K16M36RB-125:A	MT44K32M18RB-093E IT:A	MT44K64M18RCT-125E:A
MT44K32M18RB-093:A	MT44K32M36RCT-125E IT:A	MT44K64M18RCT-125:A
MT44K32M18RB-093E:A	MT44K32M36RCT-125 IT:A	MT44K32M36RCT-125:A
MT44K32M18RB-107E:A	MT44K32M18RB-125E IT:A	MT44K32M18RB-125F:A
MT44K16M36RB-125E:A	MT44K16M36RB-093 IT:A	MT44K16M36RB-125F:A

Method of Identification:

Component Mark: The first character in the "country of diffusion-encapsulation" code in the component mark for product fabricated will change from "2" (Singapore) to "1" (USA). Please refer to Micron Customer Service Note-11 for detailed description of marking codes (<http://www.micron.com/products/support/csn>)

Micron Sites Affected:	Micron Manassas (MTV),Micron Singapore(Tech)
Product Ship Date:	April 2014
Sample Available:	March 2014
Qual Data Available:	March 2014

Note: Per JEDEC Standard JESD46-C Section 3.2.3; lack of acknowledgment of this PCN within 30 days constitutes acceptance of change